

isc Silicon PNP Power Transistor

2SB1371

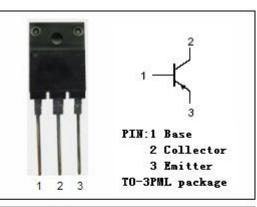
DESCRIPTION

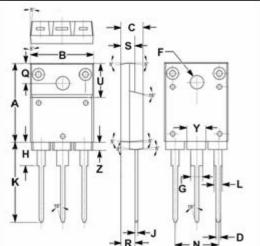
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -120V(Min)
- Good Linearity of h_{FE}
- Wide Area of Safe Operation
- Complement to Type 2SD2064
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

· Designed for high power amplifications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)				
SYMBOL	PARAMETER	VALUE	UNIT	
V _{сво}	Collector-Base Voltage	-120	V	
V _{CEO}	Collector-Emitter Voltage	-120	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
Ιc	Collector Current-Continuous	-6	A	
I _{CP}	Collector Current-Pulse	-10	A	
	Collector Power Dissipation @ T _C =25°C	70	W	
Pc	Collector Power Dissipation @ T₂=25℃	3		
TJ	Junction Temperature	150	Ĉ	
T _{stg}	Storage Temperature Range	-55~150	Ĉ	





	mm	
DIM	MIN	MAX
Α	19.90	20.10
В	15.75	16.10
С	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.20
Η	5.90	6.10
J	0.595	0.70
Κ	21.10	22.50
L	1.90	2.25
Ν	10.80	11.00
0	4.90	5.10
R	3.75	3.95
S	3.20	3.60
U	9.90	10.10
Y	4.20	4.90
Z	1.90	2.10

isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -4A; I _B = -0.4A			-2.0	V
$V_{\text{BE(on)}}$	Base -Emitter On Voltage	I _C = -4A; V _{CE} = -5V			-1.8	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -120V; I _E = 0			-50	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -3V; I _C = 0			-50	μA
h _{FE-1}	DC Current Gain	I _C = -20mA; V _{CE} = -5V	20			
h _{FE-2}	DC Current Gain	I _C = -1A; V _{CE} = -5V	60		200	
h _{FE-3}	DC Current Gain	I _C = -4A; V _{CE} = -5V	20			
f⊤	Current-Gain—Bandwidth Product	I _C = -0.5A; V _{CE} = -5 V; f= 1MHz		15		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f= 1MHz		150		pF

h_{FE-2}Classifications

Q	S	Р
60-120	80-160	100-200

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